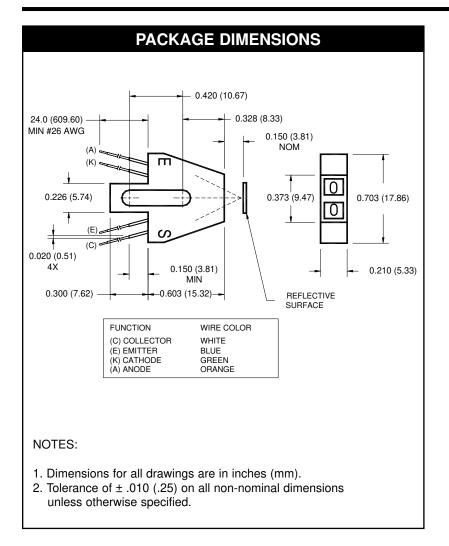
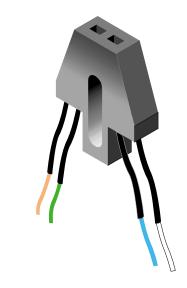
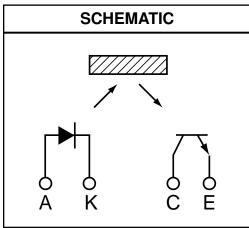


QRC1133







DESCRIPTION

The QRC1133 consists of an infrared emitting diode and an NPN silicon phototransistor mounted side by side on a converging optical axis in a black plastic housing. The phototransistor responds to radiation from the emitting diode only when a reflective object passes within its field of view. The area of the optimum response approximates a circle .200" in diameter.

FEATURES

- Phototransistor output
- · High Sensitivity
- · Low cost plastic housing
- #26 AWG, 24 inch PVC wire termination



QRC1133

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Rating	Units					
Operating Temperature	T _{OPR}	-40 to +85	°C					
Storage Temperature	T _{STG}	-40 to +85	°C					
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow)(2,3)	T _{SOL-F}	260 for 10 sec	°C					
EMITTER								
Continuous Forward Current	l _F	50	mA					
Reverse Voltage	V _R	5	V					
Power Dissipation(1)	P _D	100	mW					
SENSOR								
Collector-Emitter Voltage	V _{CEO}	30	V					
Emitter-Collector Voltage	V _{ECO}	5	V					
Collector Current	Ic	20	mA					
Power Dissipation ⁽¹⁾	P _D	100	mW					

NOTES

- 1. Derate power dissipation linearly 1.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.
- 5. D is the distance from the assembly face to the reflective surface.
- 6. Cross talk is the photo current measured with current to the input diode and no reflecting surface.
- 7. Measured using an Eastman Kodak neutral test card with 90% diffused reflecting surface.

ELECTRICAL / OPTICAL CHARACTERISTICS (T _A = 25°C)									
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS			
EMITTER		.,				.,			
Forward Voltage	$I_F = 40 \text{ mA}$	V_{F}	_	_	1.7	V			
Reverse Current	V _R = 2.0 V	I _R	_	_	100	μΑ			
Peak Emission Wavelength	I _F = 20 mA	λ_{PE}	_	940	_	nm			
SENSOR		BV _{CEO}	30	_	_	V			
Collector-Emitter Breakdown Voltage	I _C = 1 mA								
Emitter-Collector Breakdown Voltage	I _E = 0.1 mA	BV _{ECO}	5	_	_	V			
Collector-Emitter Dark Current	$V_{CE} = 10 \text{ V}, I_{F} = 0 \text{ mA}$	I _{CEO}	_	_	100	nA			
COUPLED	I _F =40mA,V _{CE} =5V,D =.150" ^(5,6)	I _{C(ON)}	0.20	_	_	mA			
On-state Collector Current	I _F =40IIIA, V _{CE} =5V,D =.150 (5)57								
Collector-Emitter	$I_F = 40 \text{ mA}, I_C = 0.1 \text{ mA}$	V _{CE (SAT)} —		_	0.4	V			
Saturation Voltage	D = 1.50"(5,7)		_						
Rise Time	V_{CE} = 5 V, R_L = 100 Ω	t _r	_	8	_	μs			
Fall Time	$I_{C(ON)} = 5 \text{ mA}$	t _f	_	8	_	μδ			
Crosstalk	$I_F = 40 \text{ mA}, V_{CE} = 5 V^{(7)}$	I _{CX}	_	_	1.00	μΑ			



QRC1133

TYPICAL PERFORMANCE CURVES

Fig. 1 Forward Voltage vs. Forward Current 1.60 1.40 VF - FORWARD VOLTAGE (V) 1.20 1.00 0.80 0.60 0.40 0.20 0.1 1.0 10 100 IF - FORWARD CURRENT (mA)

Fig. 2 Normalized Collector Current vs. Forward Current 10.0 IC - COLLECTOR CURRENT (mA) 1.00 0.10 0.01 $V_{CE} = 5 V$ D = .05'.001 0.0 10 20 30 40 IF - FORWARD CURRENT (mA)

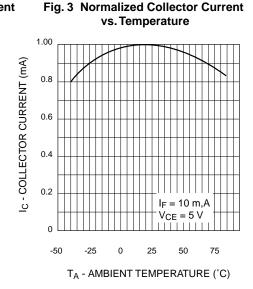
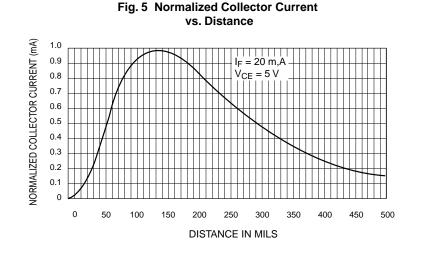


Fig. 4 Normalized Collector Dark **Current vs. Temperature** 10² I_{CEO} - COLLECTOR DARK CURRENT 10¹ V_{CE} = 10 V 10 1.0 10⁻¹ 10-2 10-3 50 -25 0 25 50 75 100 TA - AMBIENT TEMPERATURE (°C)





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